

Silicon Carbide Power Schottky Barrier Diode



Lead Free

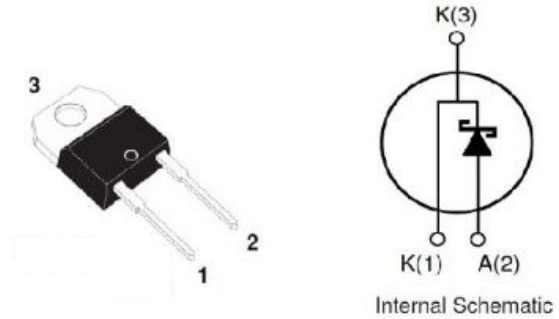
Applications:

- Power factor correction
- Solar wind inverters
- Industrial motor drivers
- Charge block for electrical cars
- Electrical household appliances
- Uninterruptible Power System(UPS)

| | | |
|-----------------------------------|-------|-----------|
| $I_F, T_c \leq 135^\circ\text{C}$ | Q_c | V_{RRM} |
| 8.5A | 16 nC | 600V |

Features:

- Rated to 600V at 5 Amps
- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behaviour
- High temperature operation
- High frequency operation
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements



Ordering Information

| Part Number | Package | Marking |
|-------------|----------|-----------|
| RSS05060A | TO-220-2 | RSS05060A |

Maximun Ratings

| Symbol | Parameter | Value | Units | Test Conditions |
|--------------------|--|----------------|--------------|--|
| VRRM | Repetitive Peak Reverse Voltage | 600 | V | T _j =25°C |
| VRSM | Surge Peak Reverse Voltage | 600 | V | T _j =25°C |
| VDC | DC Blocking Voltage | 600 | V | T _j =25°C |
| I _F | Continuous Forward Current | 19 8.5 5 | A | T _j =25°C T _j =135°C T _j =158°C |
| I _{FRM} | Repetitive Peak Forward Surge Current | 25 | A | T _c =25°C, T _p =10mS, Half Sine Wave, D=0.3 |
| I _{FSM} | Non-repetitive Peak Forward Surge Current | 35 | A | T _c =25°C, T _p =10mS, Half Sine Wave |
| P _{TOT} | Power Dissipation | 77 35 | W | T _c =25°C T _c =110°C |
| T _c | T _c | 135 | °C | |
| T _j | Maximum Case Temperature | -55 to 175 | °C | |
| T _{stg} | Operating Junction | -55 to 175 | °C | |
| TL TPKG | Maximum Temperature for Soldering Leads at 0.063in(1.6mm)from Case for 10 seconds Package Body for 10 seconds | 300 260 | °C | |
| Mounting Torque | | 1 8.8 | Nm lbf-in | M3 Screw 6-32 Screw |

Thermal Resistance

| Symbol | Parameter | Value | Units | Test Conditions |
|--------|------------------|-------|-------|-----------------|
| Rth JC | Junction-to-Case | 1.95 | °C/W | |

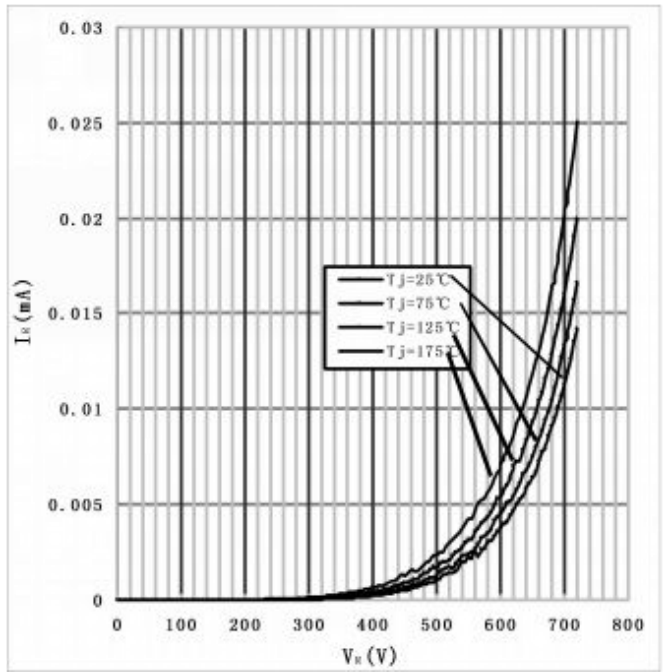
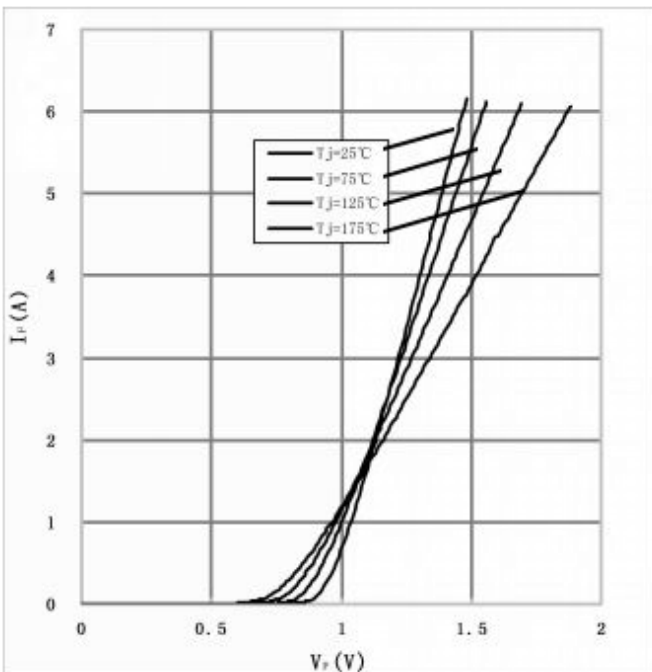
Electrical Characteristics

| Symbol | Parameter | Typ. | Max. | Units | Test Conditions |
|--------|-------------------|------|------|-------|--|
| VF | Forward Voltage | 1.4 | 1.7 | V | IF=5A Tj=25°C |
| | | 1.75 | 2.5 | | IF=5A Tj=175°C |
| IR | Reverse Current | 5 | 100 | µA | VR=600V Tj=25°C |
| | | 20 | 200 | | VR=600V Tj=175°C |
| Qc | Total Capacitive | 16 | -- | nC | VR=600V, IF=5A, di/dt=500A/us, Tj=25°C |
| C | Total Capacitance | 304 | 320 | pF | VR=0V, Tj=25°C, f=1MHZ |
| | | 32 | 34 | | VR=200V, Tj=25°C, f=1MHZ |
| | | 31.4 | 32 | | VR=400V, Tj=25°C, f=1MHZ |

Performance Graphs

Figure1. Forward IV characteristics as a function of Tj

Figure2. Reverse IV characteristics as a function of Tj



Performance Graphs

Figure3. Current Derating

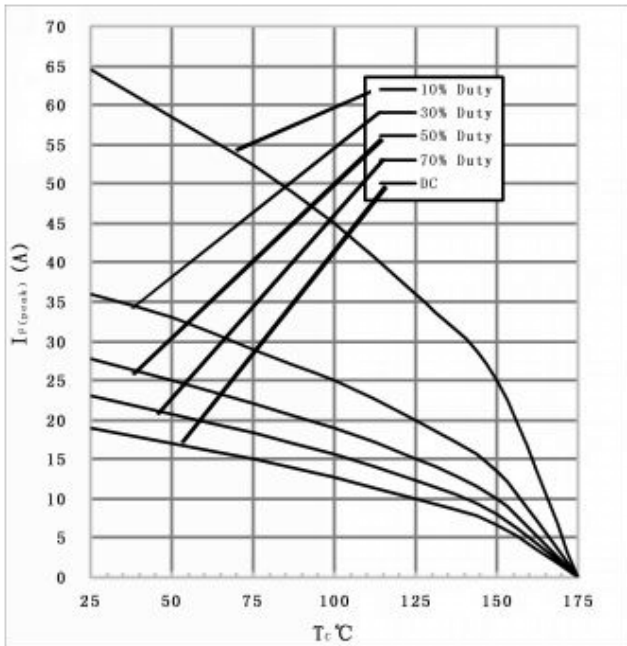
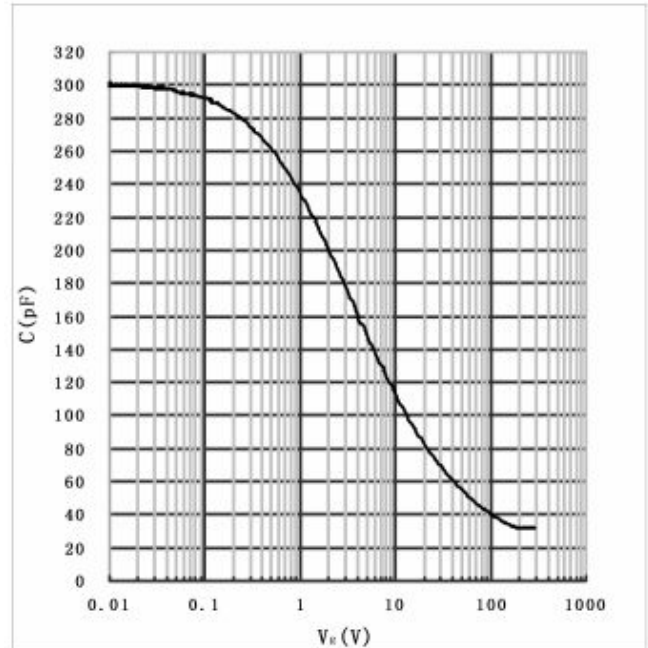
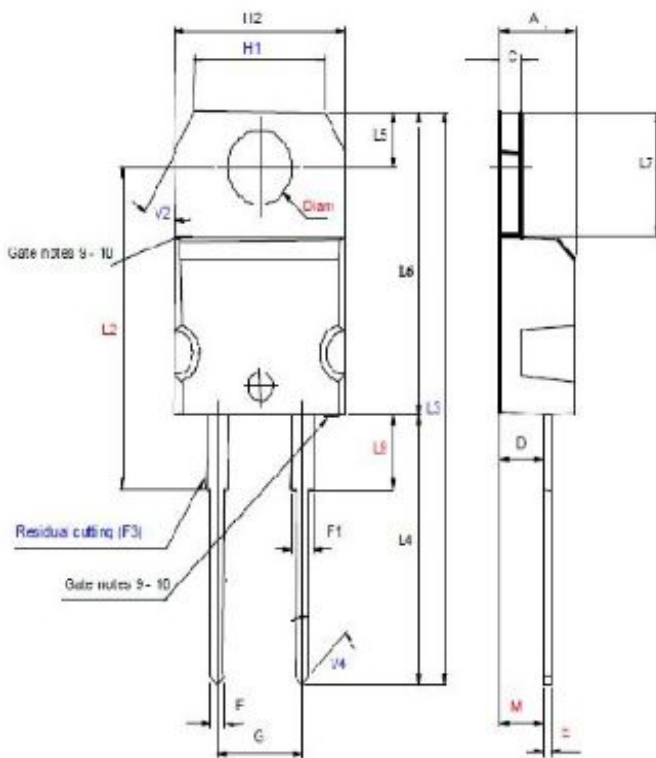


Figure4. Capacitance vs. reverse voltage



Package T0-220-2



| DIM | Millimeters | | Inches | |
|------|-------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.4 | 4.6 | 0.173 | 0.181 |
| C | 1.23 | 1.32 | 0.048 | 0.052 |
| D | 2.4 | 2.72 | 0.094 | 0.107 |
| E | 0.49 | 0.7 | 0.019 | 0.028 |
| F | 0.61 | 0.88 | 0.024 | 0.035 |
| F1 | 1.14 | 1.7 | 0.045 | 0.067 |
| F3 | | 1 | | 0.039 |
| G | 4.95 | 5.15 | 0.195 | 0.203 |
| H1 | 7.7 | 7.9 | 0.303 | 0.311 |
| H2 | 10 | 10.4 | 0.394 | 0.409 |
| L2 | 16.4 | | 0.646 | |
| L3 | 28.9 | | 1.138 | |
| L4 | 13 | 14 | 0.512 | 0.551 |
| L5 | 2.65 | 2.95 | 0.104 | 0.116 |
| L6 | 15.25 | 15.75 | 0.600 | 0.620 |
| L7 | 6.2 | 6.6 | 0.244 | 0.260 |
| L9 | 3.5 | 3.93 | 0.138 | 0.155 |
| M | 2.6 | | | |
| V | 5° | | | |
| V2 | 30° | | | |
| V4 | 45° | | | |
| diam | 3.75 | 3.85 | 0.148 | 0.152 |

Disclaimers:

GuangDong Reasunos Semiconductor Technology CO.,LTD(Reasunos)reserves the right to make changes without notice in order to improve reliability,function or design and to discontinue any product or service without notice .Customers should obtain the latest relevant information before orders and should verify that such information in current and complete.All products are sold subject to Reasunos's terms and conditions supplied at the time of order acknowledgement.

GuangDong Reasunos Semiconductor Technology CO.,LTD warrants performance of its hardware products to the specifications at the time of sale.Testing,reliability and quality control are used to the extent Reasunos deems necessary to support this warrantee. Except where agreed upon by contractual agreement,testing of all parameters of each product is not necessarily performed.

GuangDong Reasunos Semiconductor Technology CO.,LTD does not assume any liability arising from the use of any product or circuit designs described herein.Customers are responsible for their products and applications using Reasunos's components.To minimize risk,customers must provide adequate design and operating safeguards.

GuangDong Reasunos Semiconductor Technology CO.,LTD does not warrant or convey any license either expressed or implied under its patent rights,nor the rights of others.Reproduction of information in Reasunos's data sheets or data books is permissible only if reproduction is without modification or alteration.Reproduction of this information with any alteration is an unfair and deceptive business practice.GuangDong Reasunos Semiconductor Technology CO.,LTD is not responsible or liable for such altered documentation.

Resale of Reasunos's products with statements different from or beyond the parameters stated by GuangDong Reasunos Semiconductor Technology CO.,LTD for that product or service voids all express or implied warranties for the associated Reasunos's product or service and is unfair and deceptive business practice.GuangDong Reasunos Semiconductor Technology CO.,LTD is not responsible or liable for such statements.

Life Support Policy:

GuangDong Reasunos Semiconductor Technology CO.,LTD's Products are not authorized for use as critical components in life support devices or systems without the expressed written approval of GuangDong Reasunos Semiconductor Technology CO.,LTD.

As used herein:

- 1.Life support devices or systems are devices or systems which:
 - a.are intended for surgical implant into the human body,
 - b.support or sustain life,
 - c.whose failure to when properly used in accordance with instructions for use provided in the labeling,can be reasonably expected to result in significant injury to the user.
 - 2.A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system,or to affect its safety or effectiveness.
-